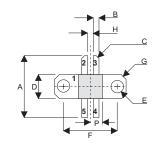
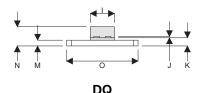


### **D1016UK**

### METAL GATE RF SILICON FET

### **MECHANICAL DATA**





PIN 1 SOURCE (COMMON) PIN 2 **DRAIN 1** PIN 3 DRAIN 2 PIN 4 GATE 2 PIN 5 GATE 1

DIM	mm	Tol.	Inches	Tol.
Α	16.38	0.26	0.645	0.010
В	1.52	0.13	0.060	0.005
С	45°	5°	45°	5°
D	6.35	0.13	0.250	0.005
Е	3.30	0.13	0.130	0.005
F	14.22	0.13	0.560	0.005
G	1.27 x 45°	0.13	0.05 x 45°	0.005
Н	1.52	0.13	0.060	0.005
- 1	6.35	0.13	0.250	0.005
J	0.13	0.02	0.005	0.001
K	2.16	0.13	0.085	0.005
М	1.52	0.13	0.060	0.005
N	5.08	MAX	0.200	MAX
0	18.90	0.13	0.744	0.005
Р	3.18	0.25	0.125	0.010

# **GOLD METALLISED MULTI-PURPOSE SILICON DMOS RF FET** 40W - 28V - 500MHz**PUSH-PULL**

### **FEATURES**

- SIMPLIFIED AMPLIFIER DESIGN
- SUITABLE FOR BROAD BAND APPLICATIONS
- VERY LOW C<sub>rss</sub>
- USEFUL P<sub>O</sub> AT 1GHz
- LOW NOISE
- HIGH GAIN 13 dB MINIMUM

### **APPLICATIONS**

 VHF/UHF COMMUNICATIONS from 1 MHz to 1 GHz

### **ABSOLUTE MAXIMUM RATINGS** (T<sub>case</sub> = 25°C unless otherwise stated)

$P_{D}$	Power Dissipation	100W
$BV_{DSS}$	Drain – Source Breakdown Voltage *	70V
$BV_{GSS}$	Gate – Source Breakdown Voltage *	±20V
I <sub>D(sat)</sub>	Drain Current *	5A
T <sub>stg</sub>	Storage Temperature	−65 to 150°C
Tj	Maximum Operating Junction Temperature	200°C

Per Side

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# **ELECTRICAL CHARACTERISTICS** (T<sub>case</sub> = 25°C unless otherwise stated)

Parameter		Test (	Min.	Тур.	Max.	Unit	
		PE	R SIDE				
D\/	Drain-Source Breakdown	\/ <b>-</b> 0	L = 100mA	70			V
BV <sub>DSS</sub>	Voltage	$V_{GS} = 0$	I <sub>D</sub> = 100mA	70			\ \ \
	Zero Gate Voltage	\/ 20\/	V 0			1	A
<sup>I</sup> DSS	Drain Current	V <sub>DS</sub> = 28V	$V_{GS} = 0$			ı	mA
I <sub>GSS</sub>	Gate Leakage Current	V <sub>GS</sub> = 20V	V <sub>DS</sub> = 0			1	μΑ
V <sub>GS(th)</sub>	Gate Threshold Voltage*	I <sub>D</sub> = 10mA	$V_{DS} = V_{GS}$	1		7	V
9 <sub>fs</sub>	Forward Transconductance*	V <sub>DS</sub> = 10V	I <sub>D</sub> = 1A	0.8			S
	TOTAL DEVICE						
G <sub>PS</sub>	Common Source Power Gain	P <sub>O</sub> = 40W		13			dB
η	Drain Efficiency	V <sub>DS</sub> = 28V	$I_{DQ} = 0.4A$	50			%
VSWR	Load Mismatch Tolerance	f = 400MHz		20:1			_
PER SIDE							
C <sub>iss</sub>	Input Capacitance	$V_{DS} = 28V$ V	$f'_{GS} = -5V  f = 1MHz$			60	pF
C <sub>oss</sub>	Output Capacitance	$V_{DS} = 28V$ $V_{GS} = 0$ $f = 1MHz$				30	pF
C <sub>rss</sub>	Reverse Transfer Capacitance	$V_{DS} = 28V$ $V_{GS} = 0$ $f = 1MHz$				2.5	pF

<sup>\*</sup> Pulse Test: Pulse Duration = 300  $\mu s$  , Duty Cycle  $\leq 2\%$ 

### HAZARDOUS MATERIAL WARNING

The ceramic portion of the device between leads and metal flange is beryllium oxide. Beryllium oxide dust is highly toxic and care must be taken during handling and mounting to avoid damage to this area.

#### THESE DEVICES MUST NEVER BE THROWN AWAY WITH GENERAL INDUSTRIAL OR DOMESTIC WASTE.

### THERMAL DATA

R <sub>THj-case</sub>	Thermal Resistance Junction – Case	Max. 1.75°C / W

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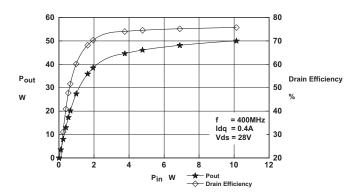


Figure 1 Power Output and efficiency vs. Power Input.

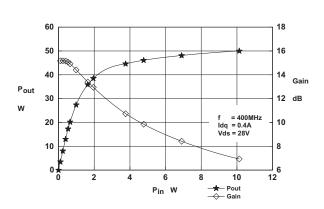


Figure 2 Power Output and Gain vs. Power Input.

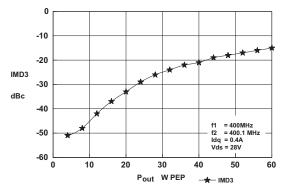


Figure 3 IMD vs. Output Power.

### **OPTIMUM SOURCE AND LOAD IMPEDANCE**

Frequency	Z <sub>S</sub>	Z <sub>L</sub>		
MHz	Ω	Ω		
400MHZ	10.7 - j35.4	13.8 - j22.2		

### **Typical S Parameters**

 $V_{DS} = 28V, I_{DQ} = 1A$ ! MHZ S MA R 50

!Freq	S11		S21		S12		S22	
!MHz	mag	ang	mag	ang	mag	ang	mag	ang
100	0.767	-135	22.646	88	0.0155	9	0.531	-103
200	0.813	-153	10.116	57	0.0099	4	0.692	-131
300	0.841	-161	5.623	39	0.0076	49	0.794	-143
400	0.861	-169	3.548	25	0.013	79	0.841	-151
500	0.882	-175	2.82	20	0.021	78	0.875	-156
600	0.902	180	2.093	14	0.0285	78	0.91	-161
700	0.923	174	1.365	9	0.0376	77	0.944	-166
800	0.912	170	1.096	2	0.0457	66	0.944	-170
900	0.923	164	0.902	-3	0.0484	66	0.933	-176
1000	0.923	161	0.724	-4	0.0596	64	0.944	-177

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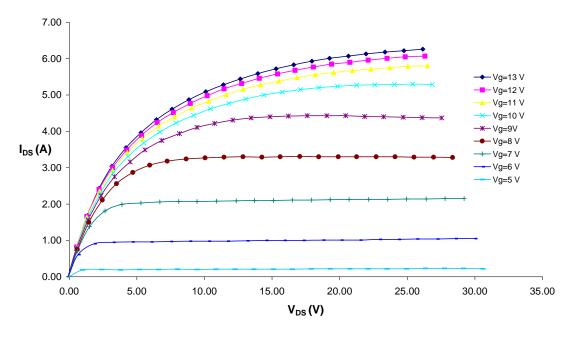


Figure 4 - Typical IV Characteristics.

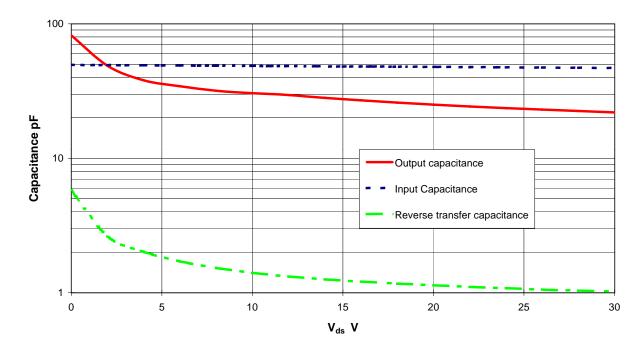


Figure 5 - Typical CV Characteristics.

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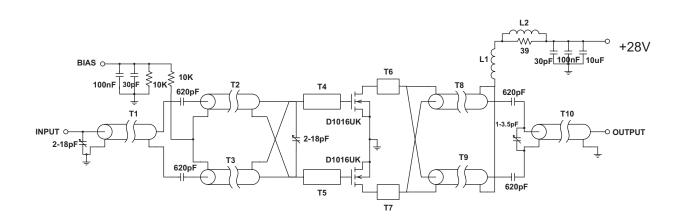
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### **TEST FIXTURE**

Substrate 1.6mm FR4 All microstrip lines W = 2.5mm

T1	45mm 50 OHM UT34 semi-rigid coax
T2, T3	55mm 50 OHM UT 34 semi-rigid coax
T4, T5	25mm microstrip line
T6, T7	10mm microstrip line
T8, T9	45mm 25 OHM UT 34-25 semi-rigid coax
T10	60mm 50OHM UT34 semi-rigid coax
L1	4 turns 19swg enamelled copper wire, 7mm i.d.
L2	2.5 turns of 19swg enamelled copper wire on T50-6 ferrite toroid

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